

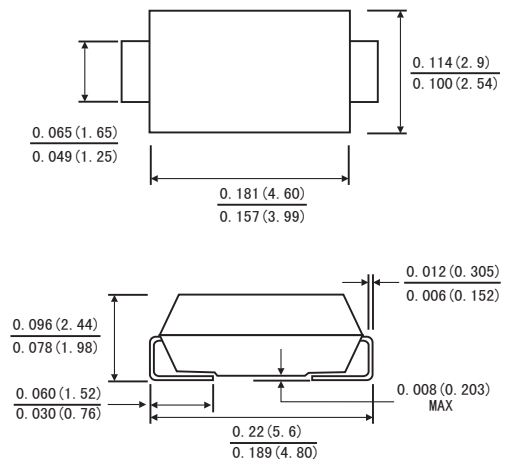
FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- For surface mount applications
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- Low profile package
- built-in strain relief ,ideal for automated placement
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 201165/EU

MECHANICAL DATA

- Case: JEDEC SMA(DO-214AC) molded plastic body
- Terminals: solder plated ,solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end

SMA(DO-214AC)



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

		Symbols	SS 32	SS 33	SS 34	SS 36	SS 310	SS 315	SS 320	Units
Maximum repetitive peak reverse voltage		VRRM	20	30	40	60	100	150	200	Volts
Maximum RMS voltage		VRMS	14	21	28	42	70	105	140	Volts
Maximum DC blocking voltage		VDC	20	30	40	60	100	150	200	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length (See Fig.1)		l(AV)	3.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		lFSM	80.0							Amps
Maximum instantaneous forward voltage at 3.0 A(Note 1)		VF	0.55			0.70	0.85	0.90	0.95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	Ta=25°C	IR	100				20			μA
	Ta=100°C		5				-			mA
	Ta=125°C		-				3			
Typical junction capacitance(Note 3)		CJ	250				160			pF
Typical thermal resistance (Note 2)		RθJA RθJL	88.0 28.0							°C/W
Operating junction temperature range		TJ	-65 to+150							°C
Storage temperature range		TSTG	-65 to+150							°C

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2. P.C.B. mounted 0.55 X 0.55"(14 X 14mm)copper pad areas

3. Measured at 1MHz and reverse voltage of 4.0volts

RATINGS AND CHARACTERISTIC CURVES SS32 THRU SS320

FIG.1-FORWARD CURRENT DERATING CURVE

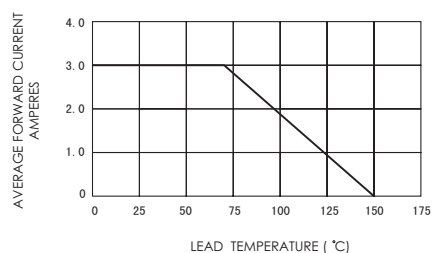


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

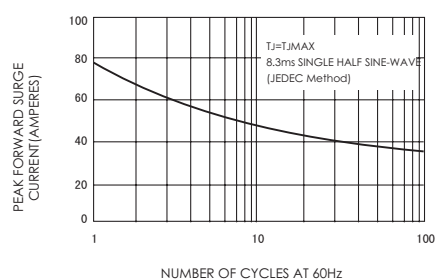


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

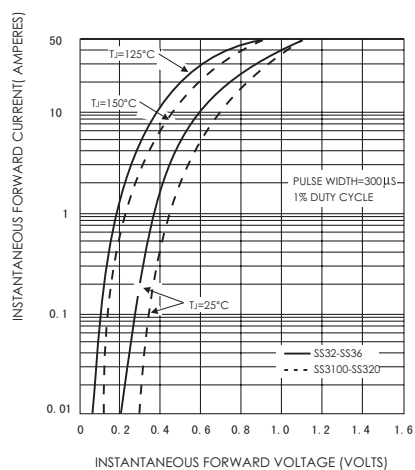


FIG.4-TYPICAL REVERSE CHARACTERISTICS

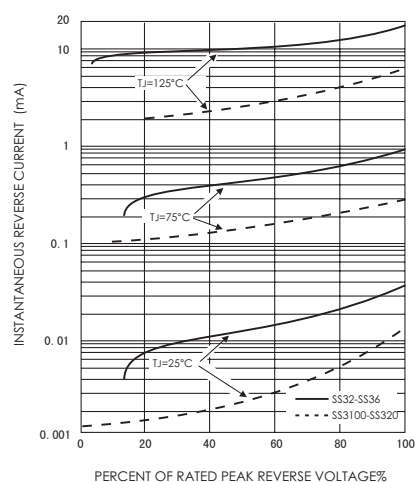
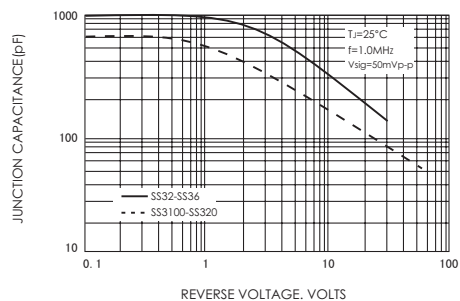


FIG.5-TYPICAL JUNCTION CAPACITANCE



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